

# MMUN2111LT1G Series

## Bias Resistor Transistors

### PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-23 package which is designed for low power surface mount applications.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SOT-23 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel.
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	246 (Note 1) 400 (Note 2) 2.0 (Note 1) 3.2 (Note 2)	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	508 (Note 1) 311 (Note 2)	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	174 (Note 1) 208 (Note 2)	$^\circ\text{C}/\text{W}$
Junction and Storage, Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

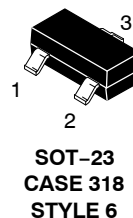
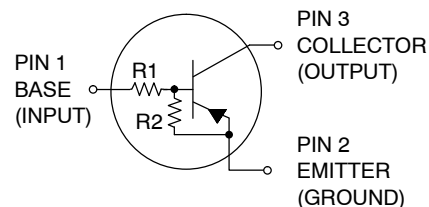
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 x 1.0 inch Pad

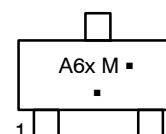


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#### MARKING DIAGRAM



A6x = Device Code  
x = A - L (Refer to page 2)  
M = Date Code\*  
■ = Pb-Free Package

(Note: Microdot may be in either location)  
\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping†
MMUN21xxLT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
MMUN21xxLT3G	SOT-23 (Pb-Free)	10000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### DEVICE MARKING INFORMATION

See specific marking information in the device marking table on page 2 of this data sheet.

# MMUN2111LT1G Series

## DEVICE MARKING AND RESISTOR VALUES

Device*	Package	Marking	R1 (K)	R2 (K)	Shipping
MMUN2111LT1G MMUN2111LT3G	SOT-23	A6A	10	10	3000/Tape & Reel 10,000/Tape & Reel
MMUN2112LT1G	SOT-23	A6B	22	22	3000/Tape & Reel
MMUN2113LT1G MMUN2113LT3G	SOT-23	A6C	47	47	3000/Tape & Reel 10,000/Tape & Reel
MMUN2114LT1G MMUN2114LT3G	SOT-23	A6D	10	47	3000/Tape & Reel 10,000/Tape & Reel
MMUN2115LT1G	SOT-23	A6E	10	∞	3000/Tape & Reel
MMUN2116LT1G	SOT-23	A6F	4.7	∞	3000/Tape & Reel
MMUN2130LT1G (Note 3)	SOT-23	A6G	1.0	1.0	3000/Tape & Reel
MMUN2131LT1G (Note 3)	SOT-23	A6H	2.2	2.2	3000/Tape & Reel
MMUN2132LT1G	SOT-23	A6J	4.7	4.7	3000/Tape & Reel
MMUN2133LT1G	SOT-23	A6K	4.7	47	3000/Tape & Reel
MMUN2134LT1G (Note 3)	SOT-23	A6L	22	47	3000/Tape & Reel

\*The "G" suffix indicates Pb-Free package available.

3. New devices. Updated curves to follow in subsequent data sheets.

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector-Base Cutoff Current ( $V_{CB} = 50\text{ V}$ , $I_E = 0$ )	$I_{CBO}$	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE} = 50\text{ V}$ , $I_B = 0$ )	$I_{CEO}$	-	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$	-	-	0.5	mAdc
	MMUN2111LT1G	-	-	0.2	
	MMUN2112LT1G	-	-	0.1	
	MMUN2113LT1G	-	-	0.2	
	MMUN2114LT1G	-	-	0.9	
	MMUN2115LT1G	-	-	1.9	
	MMUN2116LT1G	-	-	4.3	
	MMUN2130LT1G	-	-	2.3	
	MMUN2131LT1G	-	-	1.5	
	MMUN2132LT1G	-	-	0.18	
	MMUN2133LT1G	-	-	0.13	
	MMUN2134LT1G	-	-		
Collector-Base Breakdown Voltage ( $I_C = 10\ \mu\text{A}$ , $I_E = 0$ )	$V_{(BR)CBO}$	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 4) ( $I_C = 2.0\text{ mA}$ , $I_B = 0$ )	$V_{(BR)CEO}$	50	-	-	Vdc

4. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%



## MMUN2111LT1G Series

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Typ	Max	Unit
<b>ON CHARACTERISTICS</b> (Note 5)						
Input Resistor	MMUN2111LT1G	R1	7.0	10	13	k $\Omega$
	MMUN2112LT1G		15.4	22	28.6	
	MMUN2113LT1G		32.9	47	61.1	
	MMUN2114LT1G		7.0	10	13	
	MMUN2115LT1G		7.0	10	13	
	MMUN2116LT1G		3.3	4.7	6.1	
	MMUN2130LT1G		0.7	1.0	1.3	
	MMUN2131LT1G		1.5	2.2	2.9	
	MMUN2132LT1G		3.3	4.7	6.1	
	MMUN2133LT1G		3.3	4.7	6.1	
MMUN2134LT1G	15.4	22	28.6			
Resistor Ratio	MMUN2111LT1G	R <sub>1</sub> /R <sub>2</sub>	0.8	1.0	1.2	
	MMUN2112LT1G		0.8	1.0	1.2	
	MMUN2113LT1G		0.8	1.0	1.2	
	MMUN2114LT1G		0.17	0.21	0.25	
	MMUN2115LT1G		–	–	–	
	MMUN2116LT1G		–	–	–	
	MMUN2130LT1G		0.8	1.0	1.2	
	MMUN2131LT1G		0.8	1.0	1.2	
	MMUN2132LT1G		0.8	1.0	1.2	
	MMUN2133LT1G		0.055	0.1	0.185	
MMUN2134LT1G	0.38	0.47	0.56			

5. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%

# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2111LT1

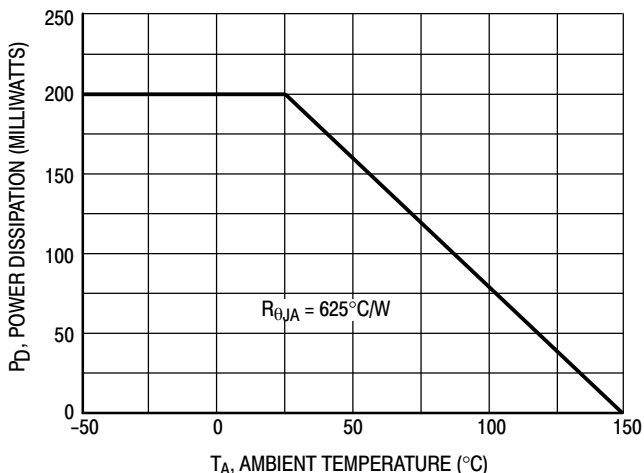


Figure 1. Derating Curve

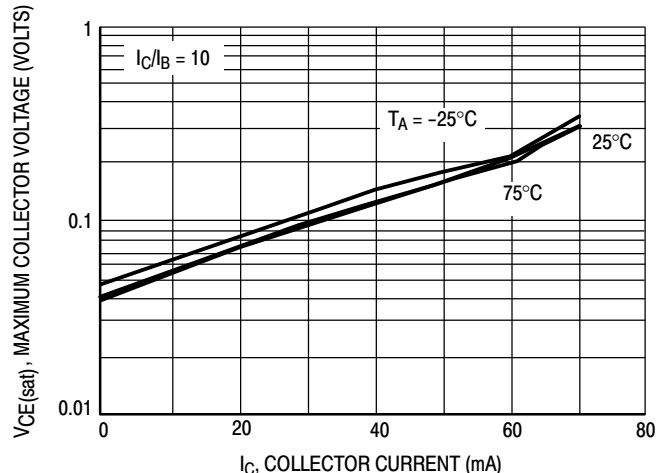


Figure 2.  $V_{CE(sat)}$  versus  $I_C$

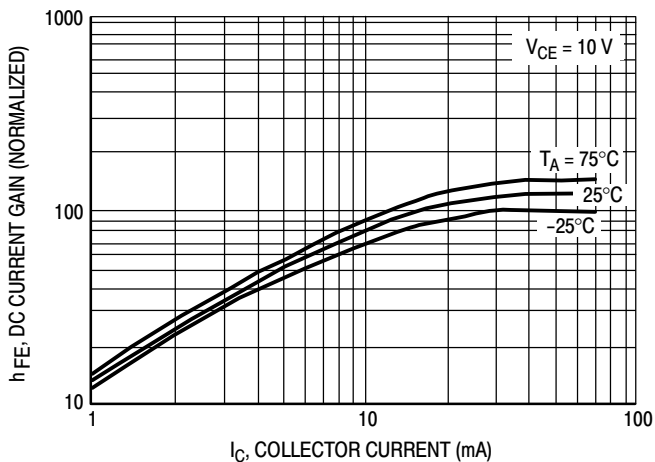


Figure 3. DC Current Gain

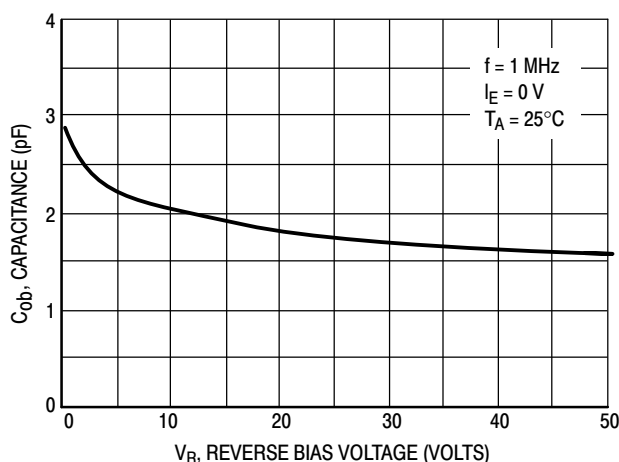


Figure 4. Output Capacitance

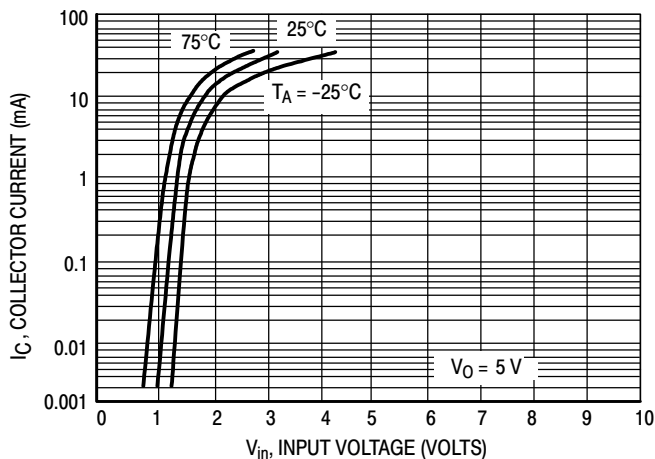


Figure 5. Output Current versus Input Voltage

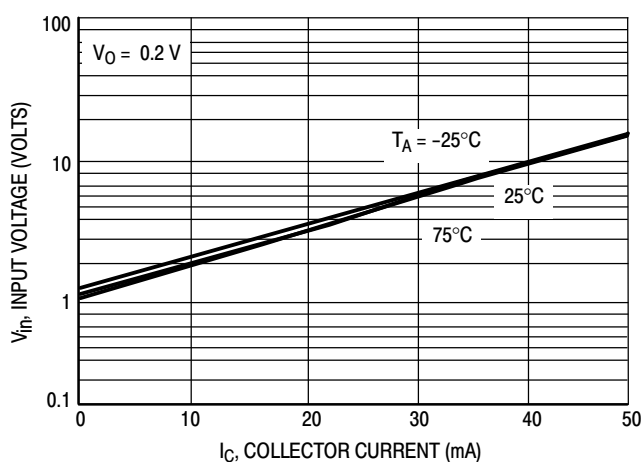


Figure 6. Input Voltage versus Output Current

# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2112LT1

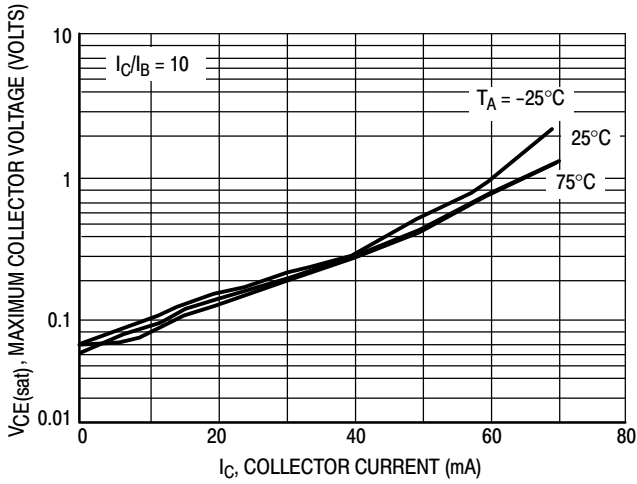


Figure 7.  $V_{CE(sat)}$  versus  $I_C$

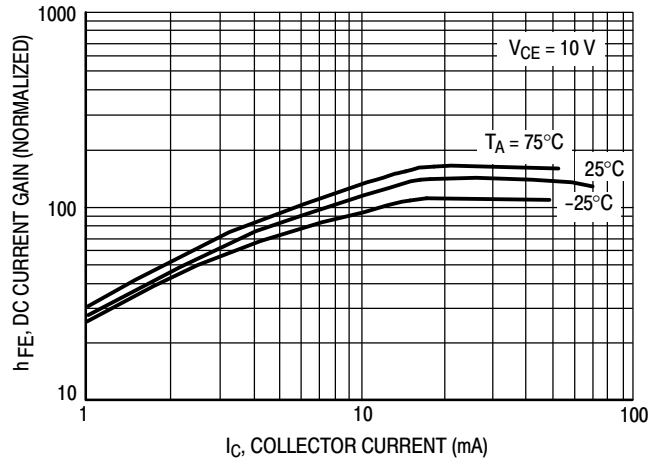


Figure 8. DC Current Gain

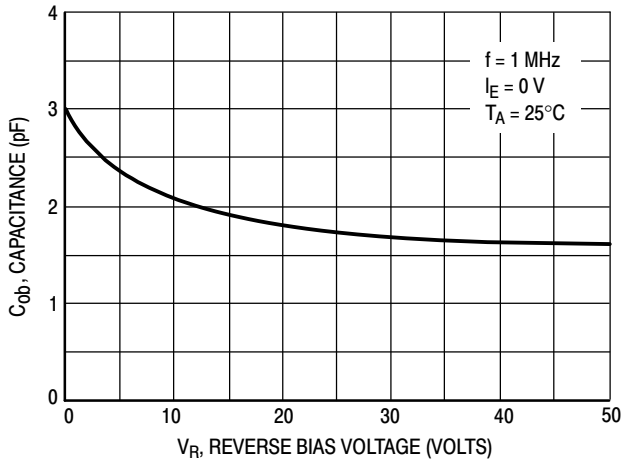


Figure 9. Output Capacitance

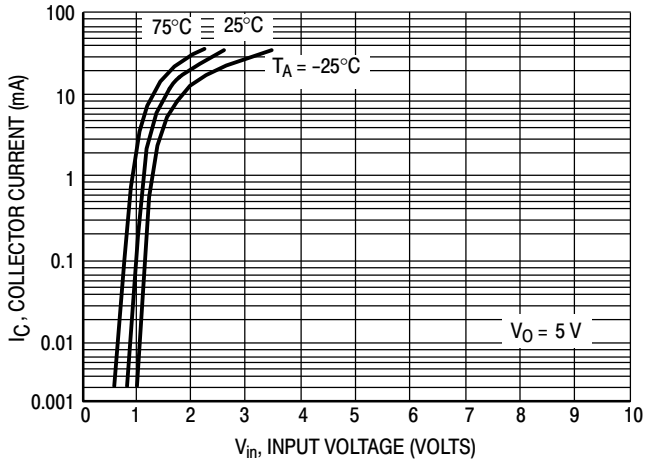


Figure 10. Output Current versus Input Voltage

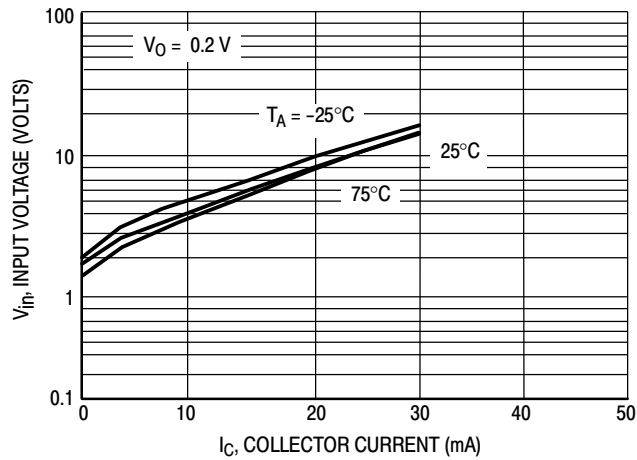


Figure 11. Input Voltage versus Output Current

# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2113LT1

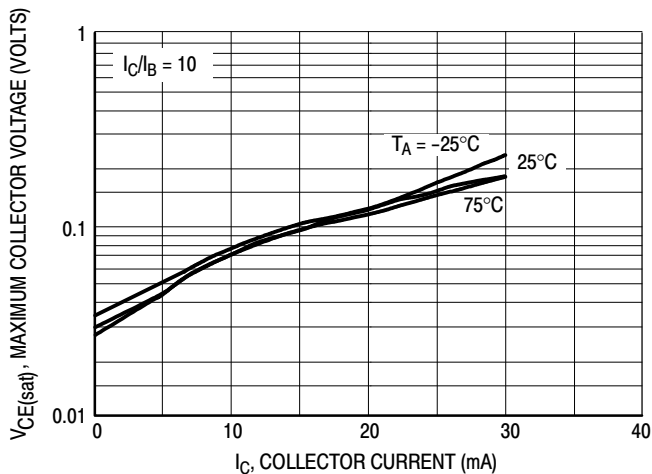


Figure 12.  $V_{CE(sat)}$  versus  $I_C$

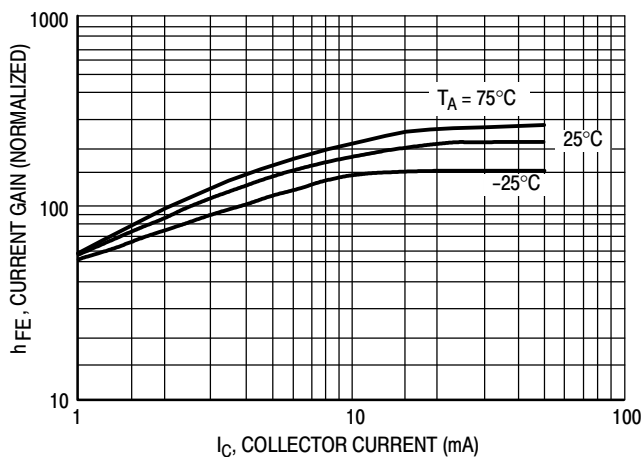


Figure 13. DC Current Gain

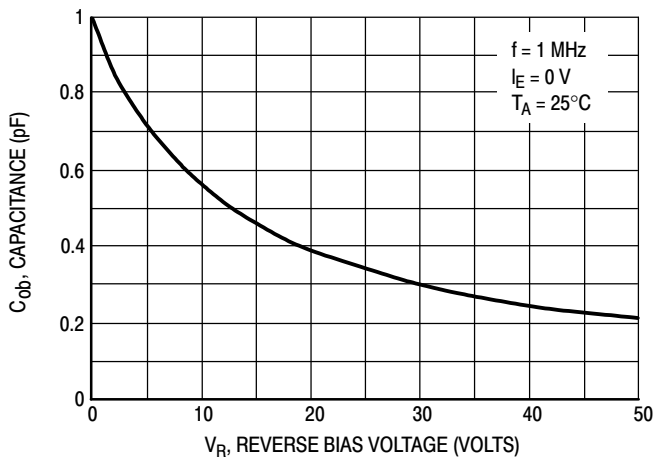


Figure 14. Output Capacitance

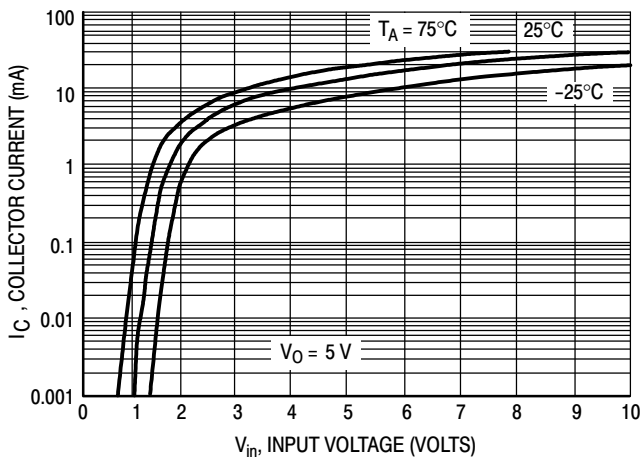


Figure 15. Output Current versus Input Voltage

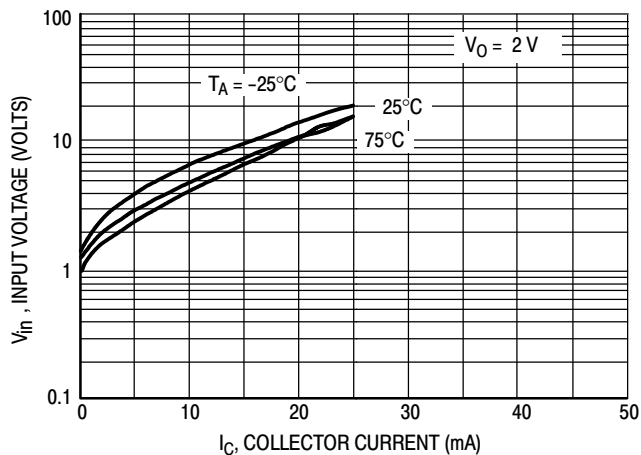


Figure 16. Input Voltage versus Output Current

# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2114LT1

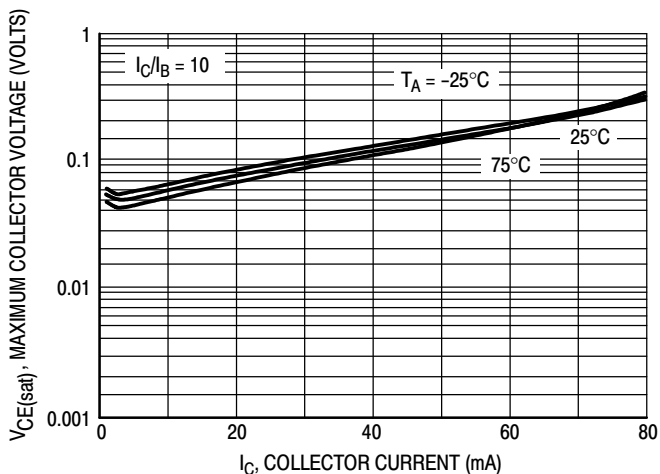


Figure 17.  $V_{CE(sat)}$  versus  $I_C$

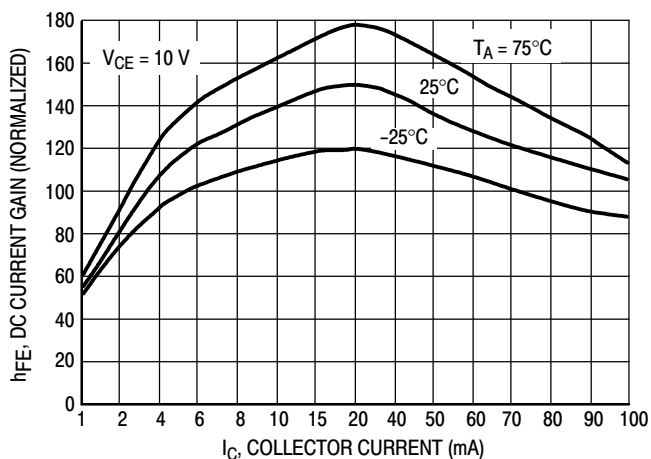


Figure 18. DC Current Gain

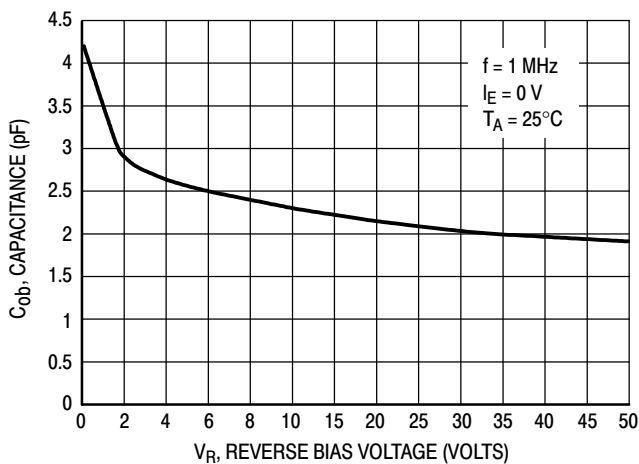


Figure 19. Output Capacitance

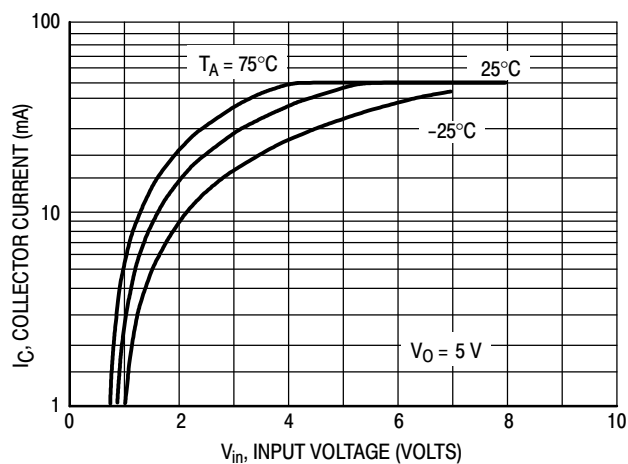


Figure 20. Output Current versus Input Voltage

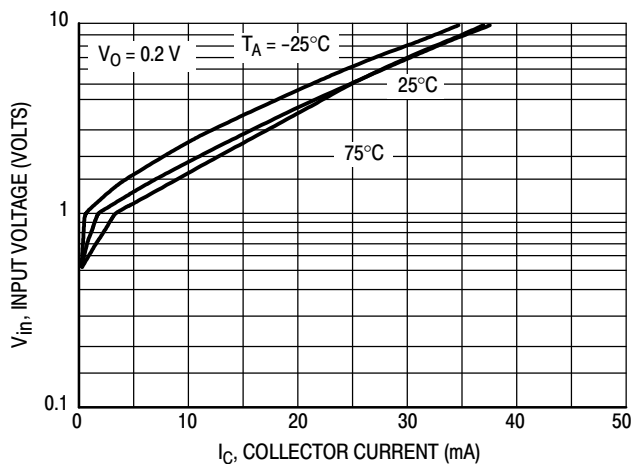


Figure 21. Input Voltage versus Output Current



# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2115LT1

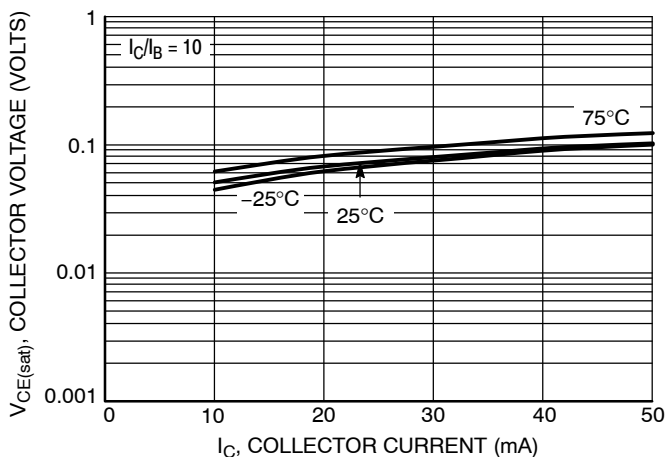


Figure 22.  $V_{CE(sat)}$  versus  $I_C$

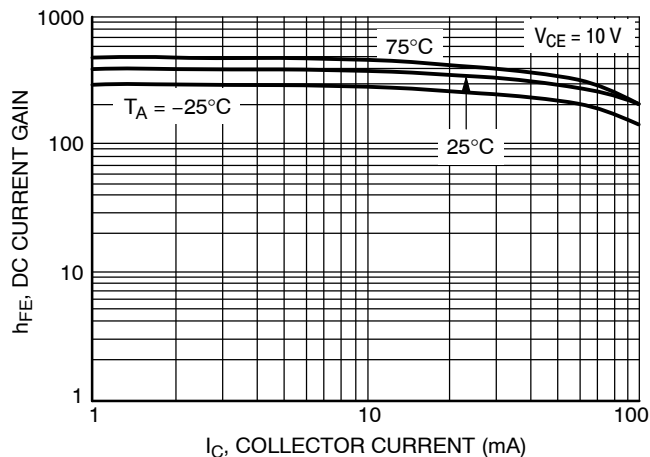


Figure 23. DC Current Gain

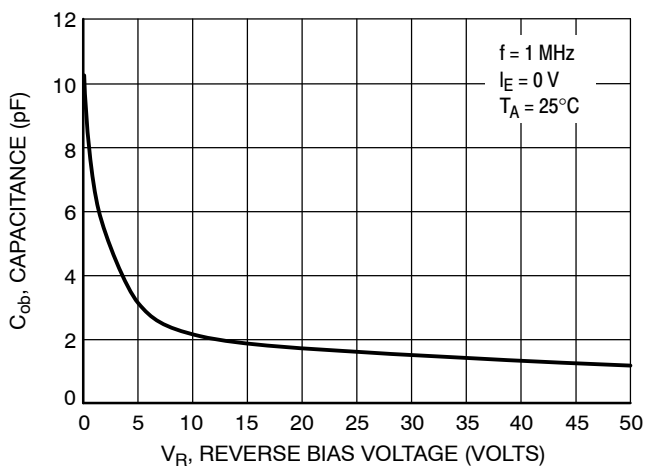


Figure 24. Output Capacitance

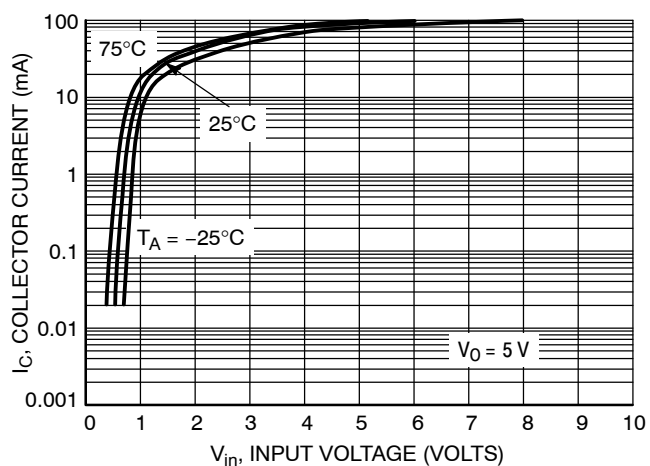


Figure 25. Output Current versus Input Voltage

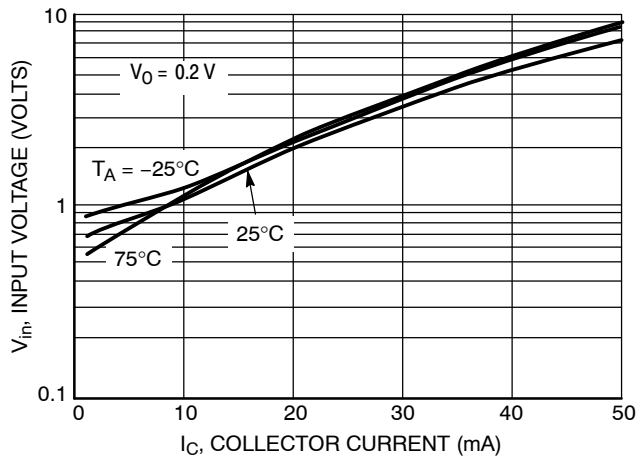


Figure 26. Input Voltage versus Output Current

# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2116LT1

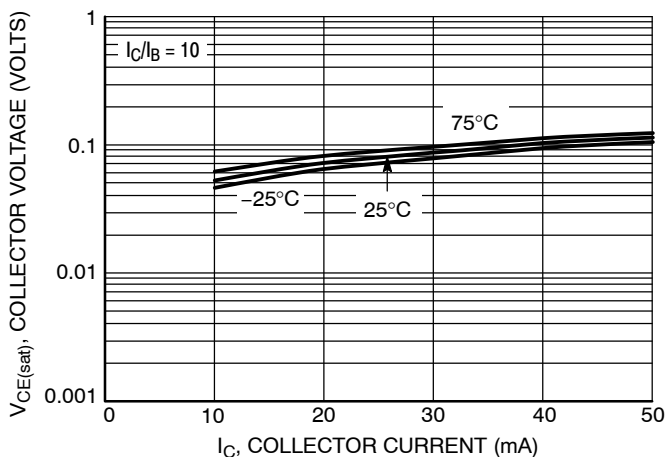


Figure 27.  $V_{CE(sat)}$  versus  $I_C$

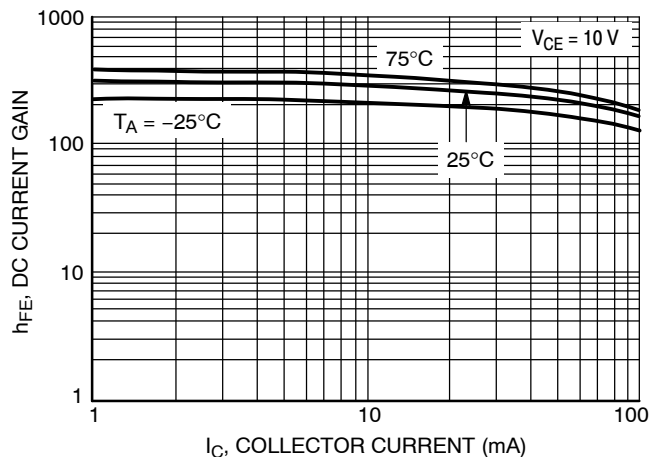


Figure 28. DC Current Gain

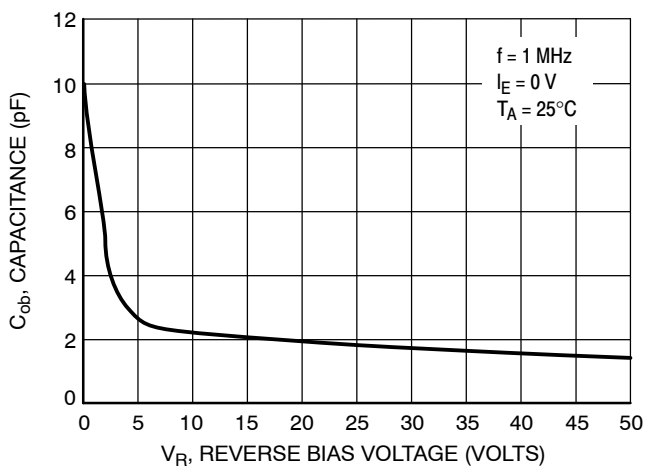


Figure 29. Output Capacitance

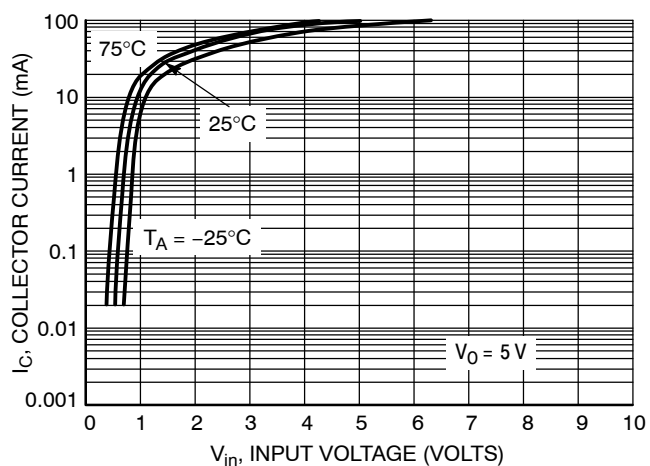


Figure 30. Output Current versus Input Voltage

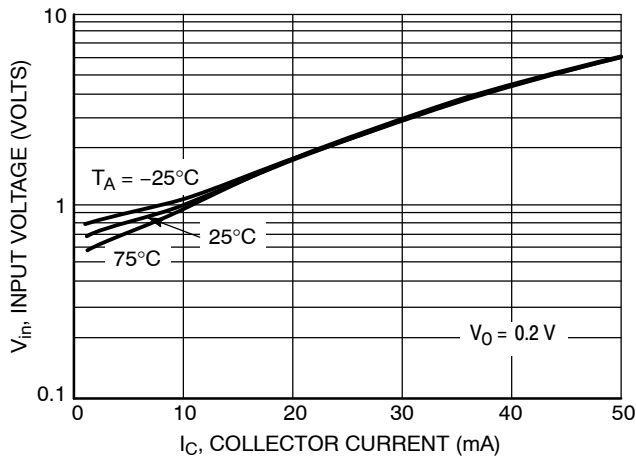


Figure 31. Input Voltage versus Output Current

# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2132LT1

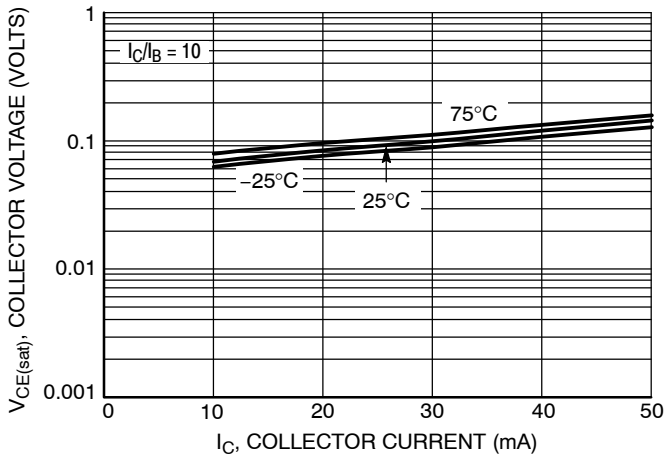


Figure 32.  $V_{CE(sat)}$  versus  $I_C$

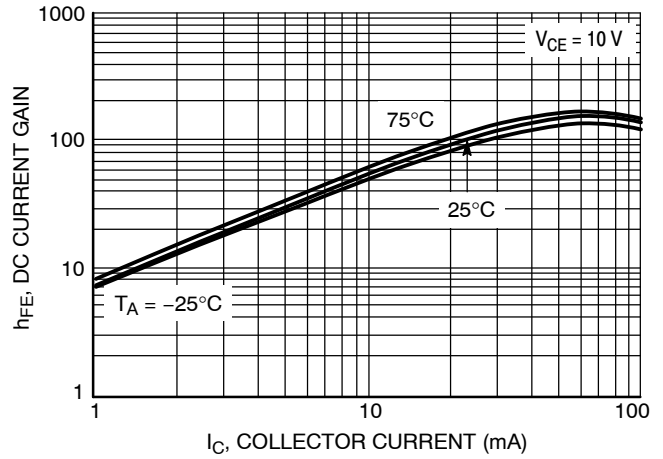


Figure 33. DC Current Gain

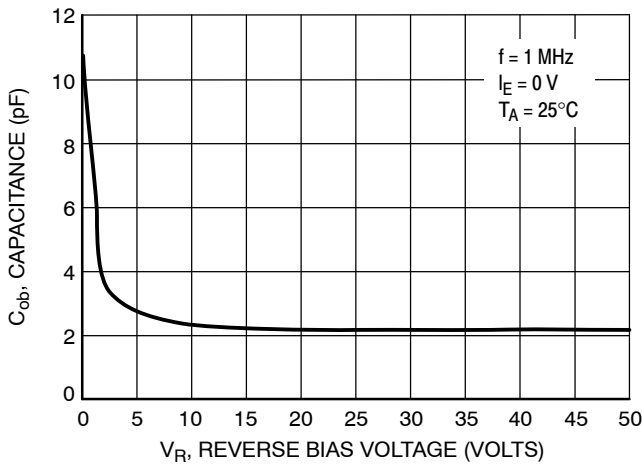


Figure 34. Output Capacitance

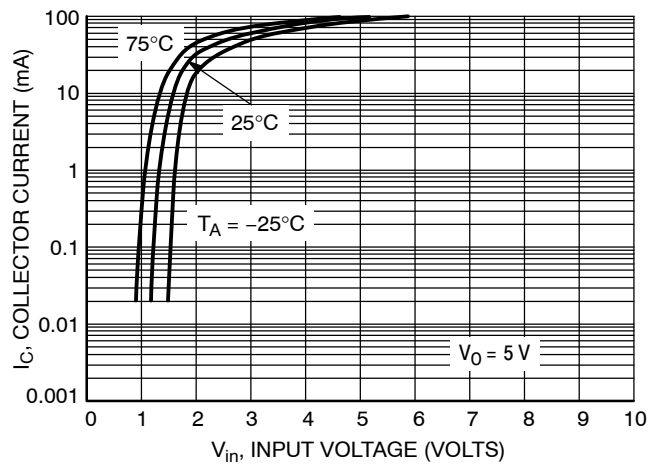


Figure 35. Output Current versus Input Voltage

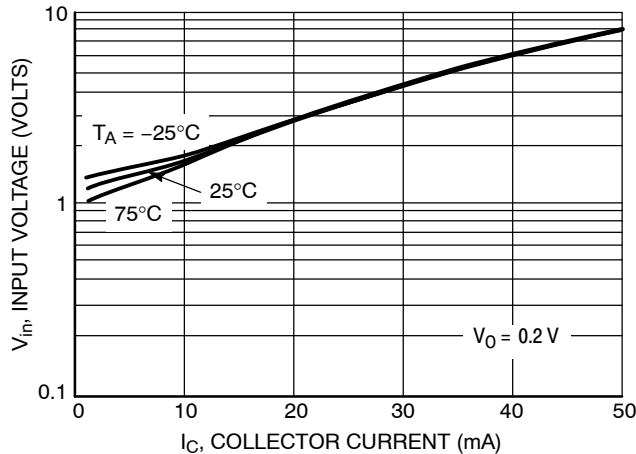


Figure 36. Input Voltage versus Output Current

# MMUN2111LT1G Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2133LT1

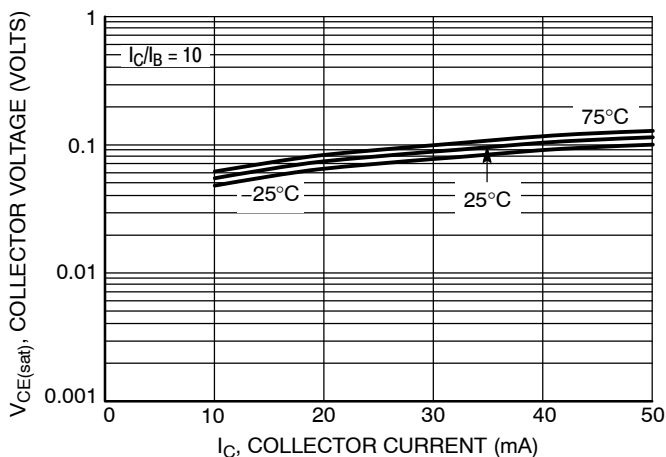


Figure 37.  $V_{CE(sat)}$  versus  $I_C$

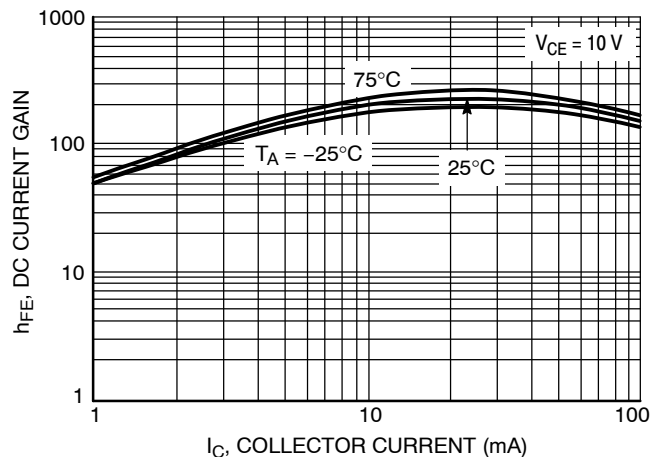


Figure 38. DC Current Gain

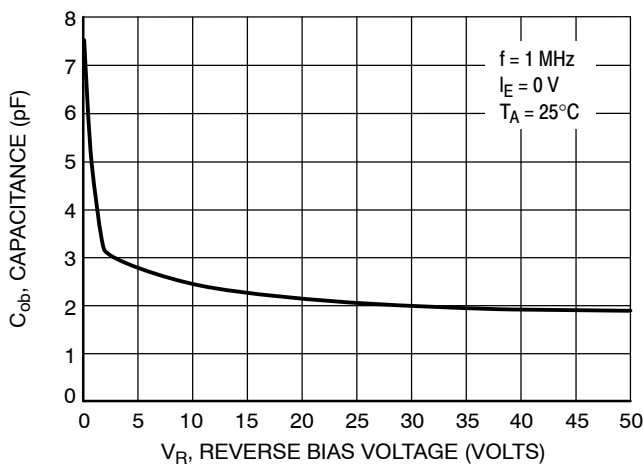


Figure 39. Output Capacitance

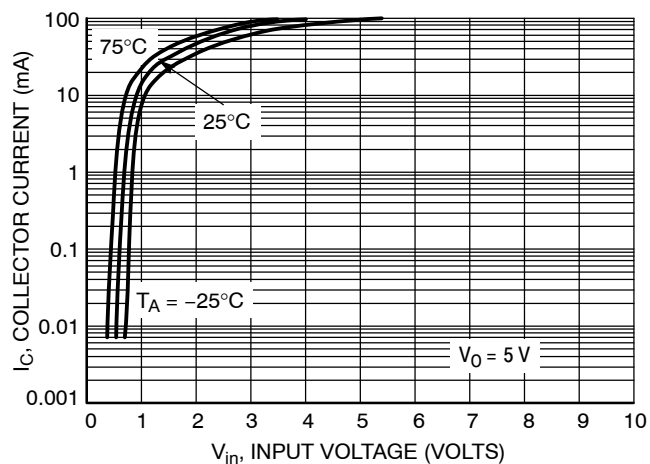


Figure 40. Output Current versus Input Voltage

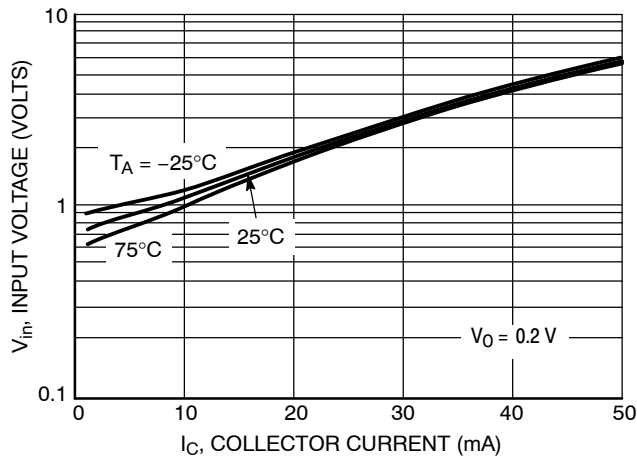


Figure 41. Input Voltage versus Output Current

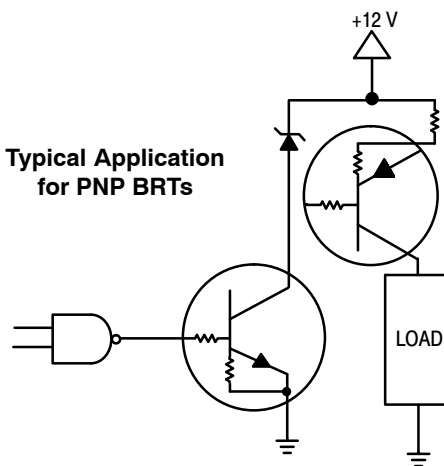
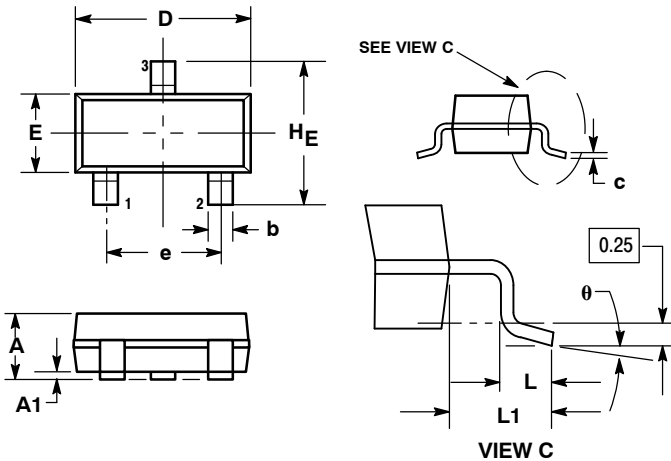


Figure 42. Inexpensive, Unregulated Current Source

# MMUN2111LT1G Series

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AN



NOTES:

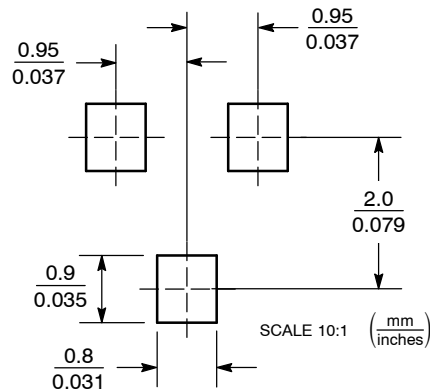
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

- PIN 1. BASE
- EMITTER
- COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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